

SANYO Semiconductors DATA SHEET

TN5D41—Separately-Excited Step-Down Switching Regulator (5V Output type)

Features

- High efficiency (ON resistance $100m\Omega$).
- Over current protection function (Self recovery type).
- · Under voltage protection function.
- Over temperature protection function (Self recovery type).
- · Soft start function (Variable subject to externally-connected capacitor).
- Stand-by mode function (Compatible with soft start terminal).

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Input Voltage	V _{IN} max		57	٧
Maximum Output Current	IO max		5	Α
SW Pin Application Reverse Voltage	Vsw		-1.5	V
FB Pin Maximum Input Voltage	V _{fb}		7	V
SS Pin Maximum Input Voltage	Vss		7	V
Allowable Power Dissipation	Do.		2.0	W
	PD	Tc=25°C	15	W
Operating Temperature	Topr		-25 to +125	°C
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Recommend Operating Conditions

Parameter	Symbol	Conditions	Ratings	Unit
Input Voltage	VIN	Ta=25°C	10 to 40	V
Output Current	IOUT	Ta=25°C	0 to 5	Α
Operating Temperature Range	Topr rec		-10 to +85	°C

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TN5D41

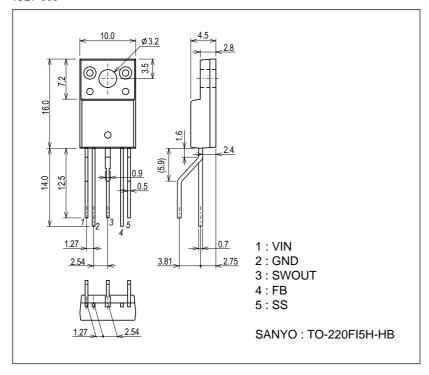
Electrical Characteristics at Ta=25°C, See Specified Test Circuit

Parameter	Symbol	Conditions	Ratings			Unit	
i didilictoi	Cymbol	Conditions	min	typ	max	ax	
Output Voltage	VOUT	V _{IN} =20V, I _{OUT} =3A	4.88	5.0	5.17	٧	
Efficiency	η	V _{IN} =20V, I _{OUT} =3A		88		%	
Drain-to-Source On Resistance	RDS(on)	ISW=5A		100		mΩ	
Switching Frequency	Freq	V _{IN} =20V, I _{OUT} =3A	120	150	180	kHz	
Maximum Duty	Duty max	V _{IN} =20V, V _{fb} =0V	88	92	96	%	
Line Regulation	ΔVline	V _{IN} =20 to 40V, I _{OUT} =3A		75	150	mV	
Load Regulation	∆Vload	V _{IN} =20V, I _{OUT} =0.5 to 5A		50	100	mV	
Output Voltage Temperature Coefficient *1	ΔV _O / ΔTa	V _{IN} =20V, I _{OUT} =3A, Ta= -25 to +125°C		±1.2		mV / °C	
Over-Current-Protection-Operation	1	VIN=20V	5.1	7.5		Α	
-Threshold Current	Іоср	VIIV=20V	5.1	7.5			
Under-Voltage-Protection-Operation	Vuvlo on		7.2	8.0	8.8	V	
-Threshold Voltage	Vavio on		1.2	0.0	0.0	V	
Under-Voltage-Protection-Operation	Vuvlo off		8.1	9.0	9.9	V	
Release Voltage	Vavio oii		0.1	3.0	3.3		
Under-Voltage-Protection Hysteresis Voltage	Vuvlo hys			1.0		٧	
Over-Temperature-Protection-Operation	Ttsd on			165		°C	
-Threshold-Current *1	1130 011			105			
Over-Temperature-Protection-Operation	Ttsd off			140		°C	
Release Temperature *1	r tsu oii			140			
Over-Temperature-Protection	Ttsd hys			25		°C	
Hysteresis Temperature *1	i tou nys			2.5			
SS Terminal Current	ISS	V _{IN} =20V		10		μΑ	
Standby Operating Voltage	Vstb on	V _{IN} =20V		0.3		٧	
Standby Current	Istb	V _{IN} =20V, V _S S=0V			500	μΑ	

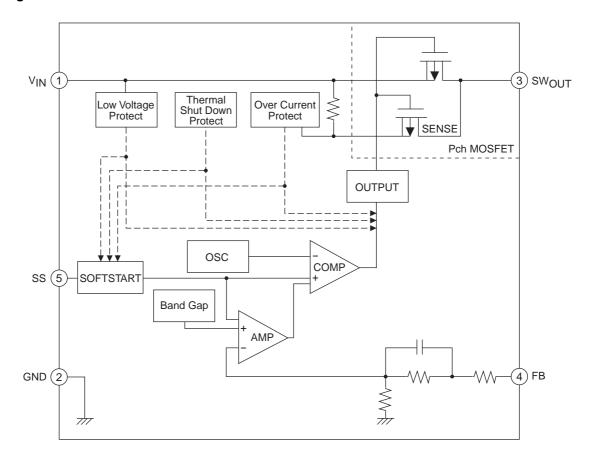
Note: the values with "*1" are our targeted values, but not guaranteed.

Package Dimensions

unit : mm (typ) 7527-001



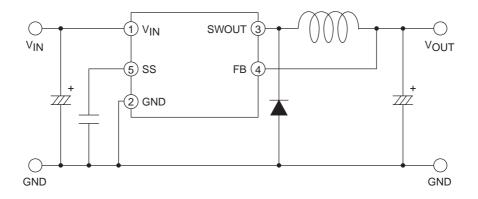
Block Diagram



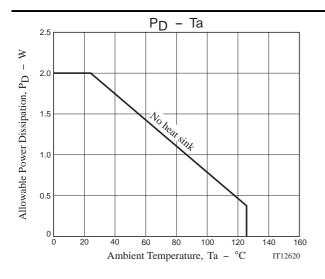
Pin Functions

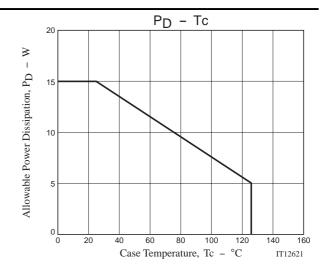
Pin No.	Symbol	Function
1	VIN	Power Supply Input (Maximum 57V)
2	GND	GND
3	SWOUT	Pulse Voltage Output
4	FB	Feedback from Output Voltage
5	SS	For Soft Start Capacitor Connection and Standby Mode Switching

Application Circuit Example



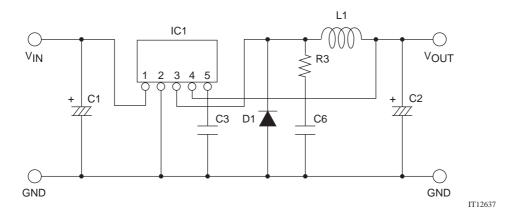
TN5D41





Specified Circuit for Electrical Characteristics

[Circuit]



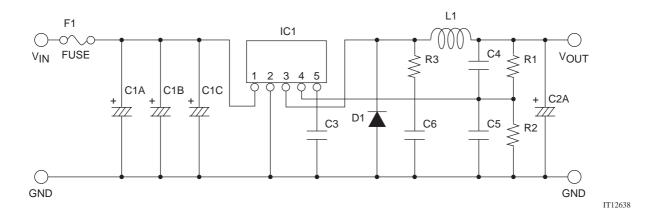
[Components]

Symbol	Component	Specification
C1	Electrolytic Capacitor	3000 to 3600μF
C2	Electrolytic Capacitor	2000 to 2200μF
C3	Capacitor	0.1μF
C6	Ceramic Capacitor	1000pF
R3	Metal Oxide Film Resistor	47Ω / 2W
L1	Choke Coil	100μΗ
D1	Schottky Barrier Diode	SBT250-06J

^{*} When measuring ripple noise voltage, put 47µF (electrolytic capacitor) and 0.1µF (ceramic or film capacitor) into measuring point.

Evaluation Board

[Circuit]

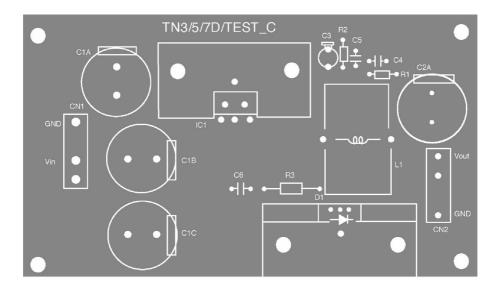


[Components]

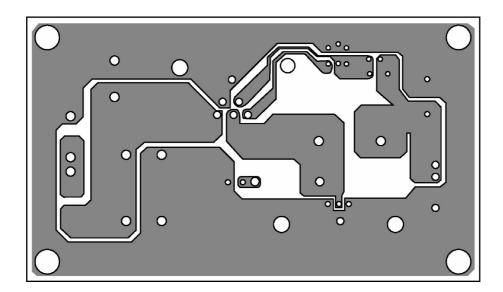
Symbol	Component	Specification	Maker	Remark
F1	Fuse	4A	Littelfuse	452 004
C1A	Electrolytic Capacitor	1200μF / 80V	Nippon Chemi-Con Corp.	KZE
C1B	Electrolytic Capacitor	1200μF / 80V	Nippon Chemi-Con Corp.	KZE
C1C	Electrolytic Capacitor	1200μF / 80V	Nippon Chemi-Con Corp.	KZE
C2A	Electrolytic Capacitor	2200μF / 35V	Nippon Chemi-Con Corp.	KMG
C3	Film Capacitor	0.1μF / 100V	Matsushita Electronic Components Corp.	ECQ-B
C4	N.C.			
C5	N.C.			
C6	Ceramic Capacitor	1000pF	Murata Manufacturing Co., Ltd	
R1	Jumper Line			
R2	N.C.			
R3	Metal Oxide Film Resistor	47Ω / 2W	Matsushita Electronic Components Corp.	
L1	Choke Coil	HK-10S100-1010	TOHO ZINC CO.,LTD	100μΗ
D1	Schottky Barrier Diode	SBT250-06J	SANYO Semiconductor Co., Ltd	

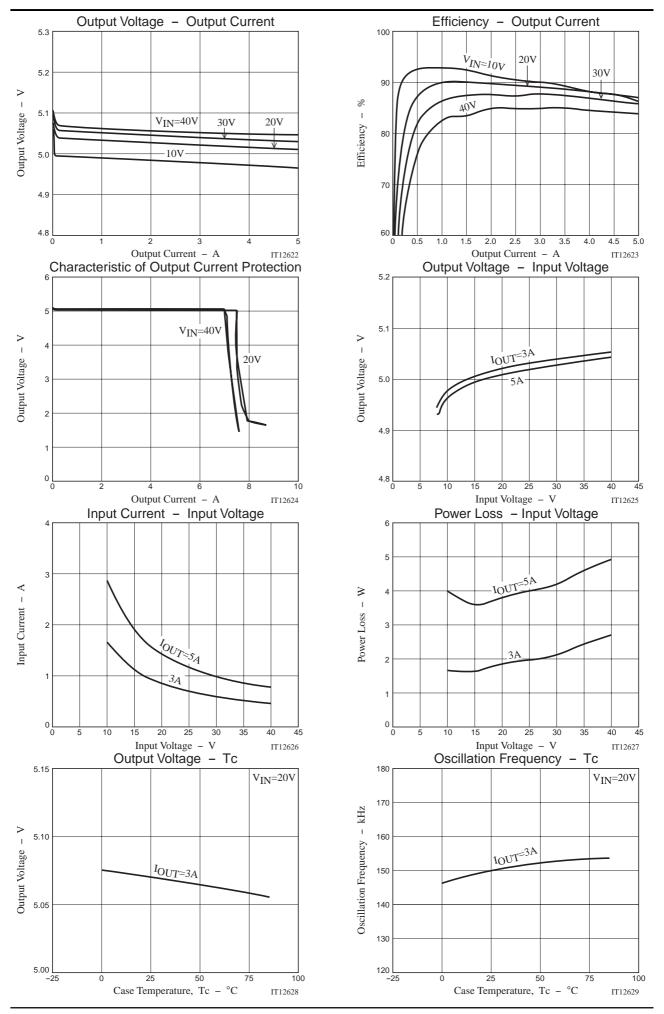
Recommended PWB Pattern

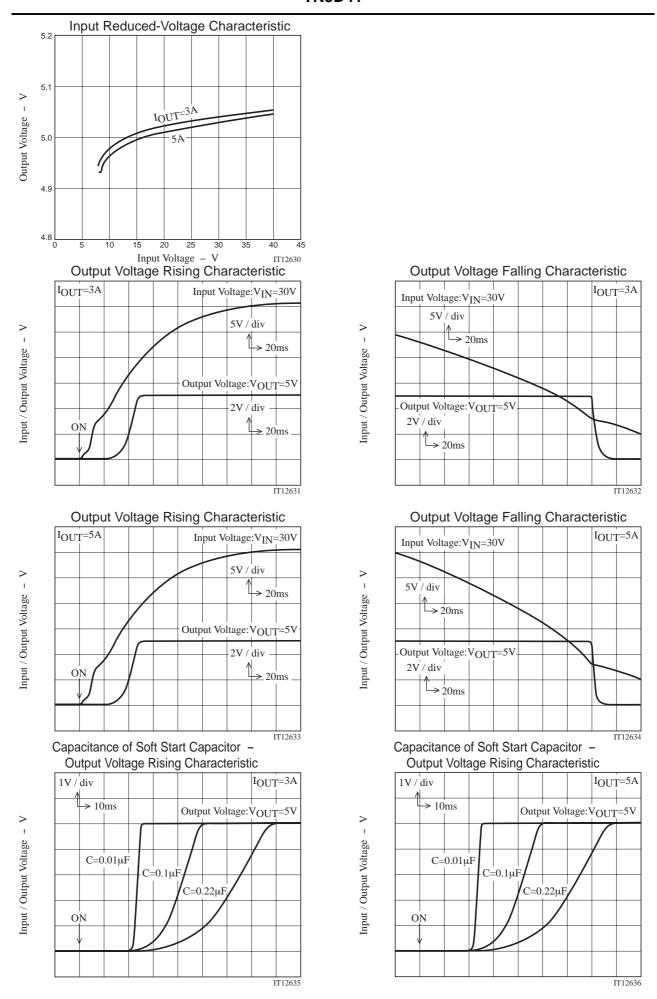
TO-220FI5H-HB Specification Silk Printing (Top View)



TO-220FI5H-HB Specification Pattern (Perspective View)







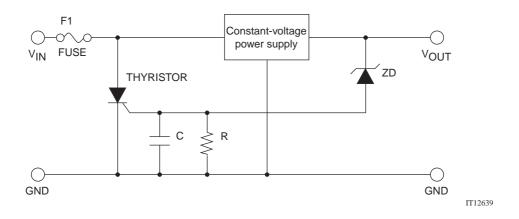
Example of Over-voltage Protection Circuit.

Generally, in constant-voltage power supply circuit, output voltage will become higher than the specified value (over-voltage state) in case of any failures or PC board solderability defects. To minimize the damage caused by this over voltage, we recommend setting an over-voltage protection circuit.

In designing, the following confirmations are necessary in actual circuit.

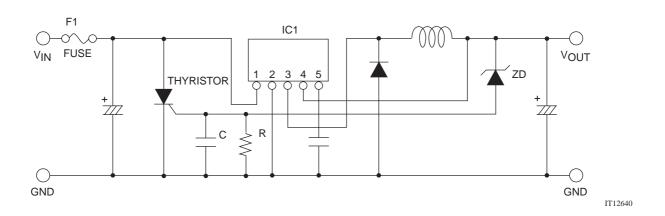
- 1) How the over-voltage protection circuit operates and its effects.
- 2) Is there any malfunction due to ambient temperature change of each device or exogenous noises?

Over-voltage Protection Circuit Example



Example of Over-voltage Protection Circuit

The thyristor will operate when it accept an over-voltage (V_{OUT}) signal, then the fuse is melted and the input power is cut off, then the operation of IC1 is stopped.

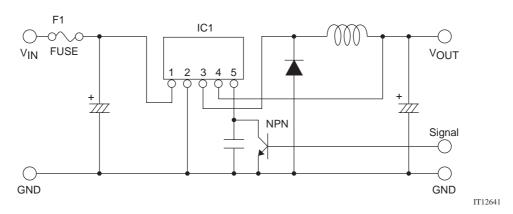


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SS terminal (5 pin) also acts as standby mode switch. By setting SS terminal (5 pin) voltage to be equal or less than 0.3Vtyp, the output ON/OFF is able to be controlled by external signals.

ON/OFF Control Circuit Example



In addition, confirmation of the following points is necessary in actual circuit.

- 1) How the output ON/OFF control operates and its effects.
- 2) Is there any malfunction due to the ambient temperature change of each device or exogenous noises?

Points to Remember in Pattern Designing

- 1) Transient large current flows to VIN terminal (1 pin), so we recommend the input capacitor should be 3000µF and above. In addition, (+) (-) terminals of the input capacitor should be set near to VIN terminal (1 pin) and GND terminal (2 pin).
- 2) Large current flows to C1A to C, V_{IN} terminal (1 pin) of IC1, SWOUT terminal (3 pin), D1, L1, and C2A. So, the wiring should be thick and short.
- 3) FB terminal (4 pin) of IC1 is the feedback terminal from output voltage. It should be near to the output capacitor C2A.
- For the purpose of ensuring the stability of oscillation, a capacitor should be inserted between SS terminal (5 pin) and GND terminal (2 pin).
- The absolute maximum rated voltage of SS terminal (5 pin) is 7V. The absolute maximum rated voltage of FB terminal (4 pin) is within the range of 5 to 30V according to the output voltage type. When a voltage equal or higher than the rated value is applied to SS terminal (5 pin) or FB terminal (4 pin) in some cases such as abnormal test, protection measures like inserting fuses should be taken.
- The built-in over-heat protection is a function to prevent the circuit from overheat state caused by transient temperature rise, but not a function to prevent from abnormal caused by a sudden heat generation. In addition, the reliability of over-heat protection function is not guarantee.

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